



Enter Part Number:
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Mass Storage : MT29F8G08ABCBBH1-12IT

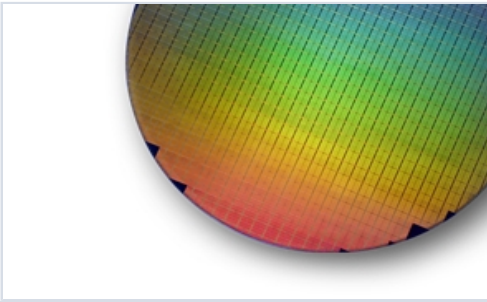
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Overview

Resources & Support

[RSS part feed:](#)

Resources



SPECIFICATIONS

Density: 8Gb
Part Status: Production
ROHS: Yes
Width: x8
Voltage: 3.3V
Package: VBGA
Pin Count: 100-ball
Bits/Cell: SLC
MT/s: 166 MT/s
I/O: Common
Op Temp: -40C to +85C

DESCRIPTION

Micron NAND Flash uses an industry-proven floating gate cell and a standard interface to enable pin and function drop-in compatibility and easy integration into most existing designs.

RoHS-Compliant: This part meets internationally recognized Pb-free standards, including RoHS.

[RoHS Certificate of Compliance](#)
[China RoHS Certificate](#)

Illustration only. See data sheet for product specifications.

Orderable Part	Part Status	Buy Samples	Distributor Stock
MT29F8G08ABCBBH1-12IT:B	Production	Contact Rep	+View

Please note: Distributor inventory is an estimate and may not reflect actual available inventory.

Some links on this page will take you from the Micron Web site. Micron does not control the content on these Web sites.

Documents

[8Gb Asynchronous/Synchronous NAND Flash Memory \(NDA - Contact Factory\)](#)
Date: 04/09
Size: 0Kb
Type: Data Sheet (PDF)

Simulation Models

HSpice
Date: 04/09
Size: 0Kb
Version: (secure)

IBIS
Date: 04/09
Size: 0Kb
Version: (secure)

Verilog
Date: 04/09
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